

# International **IR** Rectifier

HEXFRED™

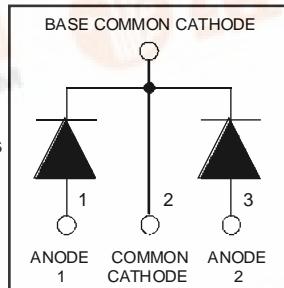
PD -2.470A

## HFA80NK40C

Ultrafast, Soft Recovery Diode

### Features

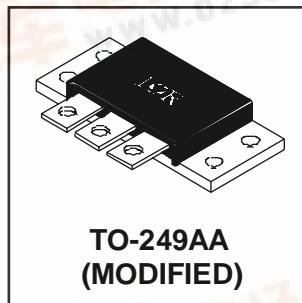
- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters



$V_R = 400V$
$V_F(\text{typ.})^{\circledcirc} = 1V$
$I_{F(AV)} = 80A$
$Q_{rr} (\text{typ.}) = 200nC$
$I_{RRM}(\text{typ.}) = 6A$
$t_{rr}(\text{typ.}) = 30ns$
$di_{(rec)M}/dt (\text{typ.})^{\circledcirc} = 190A/\mu s$

### Description

HEXFRED™ diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and  $di/dt$  simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.



### Absolute Maximum Ratings (per Leg)

	Parameter	Max.	Units
$V_R$	Cathode-to-Anode Voltage	400	V
$I_F @ T_C = 25^\circ C$	Continuous Forward Current	89	
$I_F @ T_C = 100^\circ C$	Continuous Forward Current	44	A
$I_{FSM}$	Single Pulse Forward Current ①	300	
$I_{AS}$	Maximum Single Pulse Avalanche Current ②	5.0	
$E_{AS}$	Non-Repetitive Avalanche Energy ②	1.4	mJ
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	160	W
$P_D @ T_C = 100^\circ C$	Maximum Power Dissipation	63	
$T_J$	Operating Junction and		
$T_{STG}$	Storage Temperature Range	-55 to +150	°C
	Soldering Temperature, for 10 sec.	300 (0.063 in. (1.6mm) from case)	

### Thermal - Mechanical Characteristics

	Parameter	Min.	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case, Single Leg Conducting	—	—	0.80	°C/W
	Junction-to-Case, Both Legs Conducting	—	—	0.40	K/W
$R_{\theta CS}$	Case-to-Sink, Flat , Greased Surface	—	0.10	—	
$Wt$	Weight	—	58 (2.0)	—	g (oz)
	Mounting Torque	35 (4.0)	—	50 (5.7)	lbf·in (N·m)

Note: ① Limited by junction temperature

②  $L = 100\mu H$ , duty cycle limited by max  $T_J$

③  $125^\circ C$

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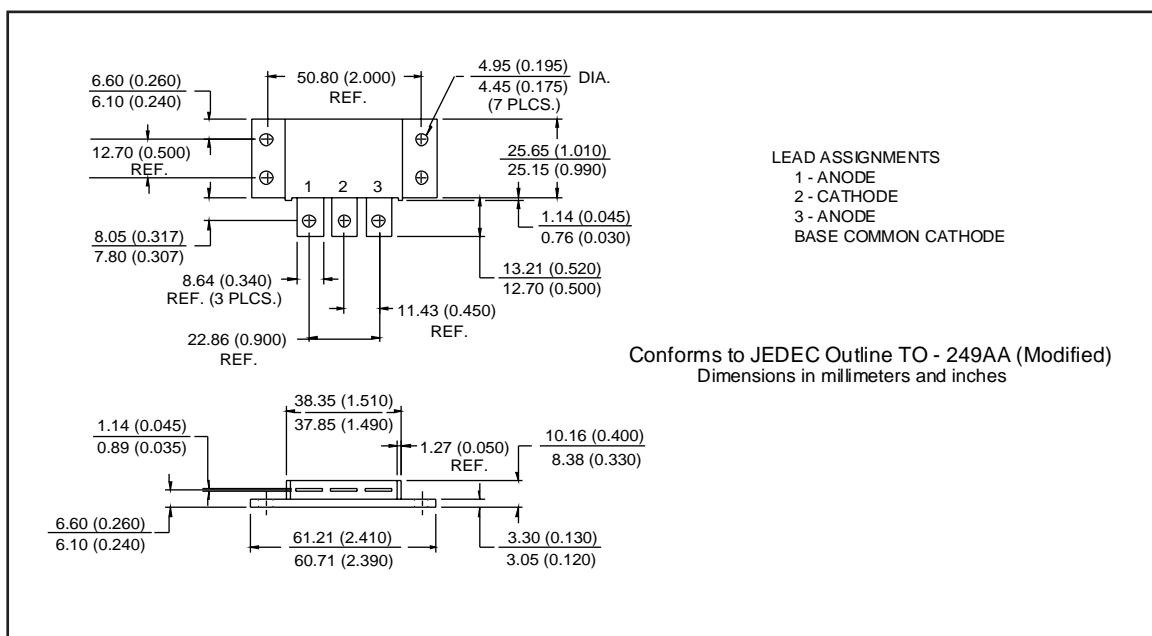
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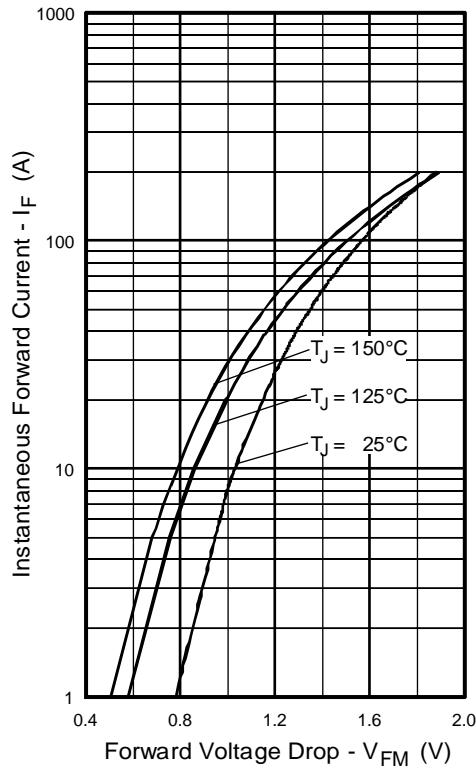
## Electrical Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
$V_{BR}$	Cathode Anode Breakdown Voltage	400	—	—	V	$I_R = 100\mu\text{A}$
$V_{FM}$	Max Forward Voltage	—	1.1	1.3	V	$I_F = 40\text{A}$
		—	1.3	1.5	V	$I_F = 80\text{A}$
		—	1.0	1.2	V	$I_F = 40\text{A}, T_J = 125^\circ\text{C}$
		—	—	—	—	See Fig. 1
$I_{RM}$	Max Reverse Leakage Current	—	0.50	3.0	$\mu\text{A}$	$V_R = V_R \text{ Rated}$
—	—	—	0.75	4.0	mA	$T_J = 125^\circ\text{C}, V_R = 320\text{V}$
$C_T$	Junction Capacitance	—	90	125	pF	$V_R = 200\text{V}$
$L_S$	Series Inductance	—	8.0	—	nH	From terminal hole to terminal hole

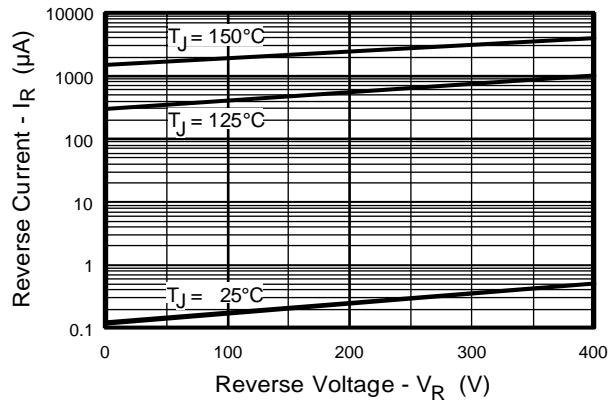
## Dynamic Recovery Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
$t_{rr}$	Reverse Recovery Time	—	30	—	ns	$I_F = 1.0\text{A}, dI/dt = 200\text{A}/\mu\text{s}, V_R = 30\text{V}$
		—	67	100	ns	$T_J = 25^\circ\text{C}$ See Fig. 5
		—	110	170	ns	$T_J = 125^\circ\text{C}$ 5
$I_{RRM1}$	Peak Recovery Current	—	6.0	11	A	$T_J = 25^\circ\text{C}$ See Fig. 6
		—	9.0	16	A	$T_J = 125^\circ\text{C}$ 6
$Q_{rr1}$	Reverse Recovery Charge	—	200	540	nC	$T_J = 25^\circ\text{C}$ See Fig. 7
		—	500	1300	nC	$T_J = 125^\circ\text{C}$ 7
$dI_{(rec)M}/dt_1$	Peak Rate of Fall of Recovery Current	—	240	—	A/ $\mu\text{s}$	$T_J = 25^\circ\text{C}$ See Fig. 8
		—	190	—	A/ $\mu\text{s}$	$T_J = 125^\circ\text{C}$ 8

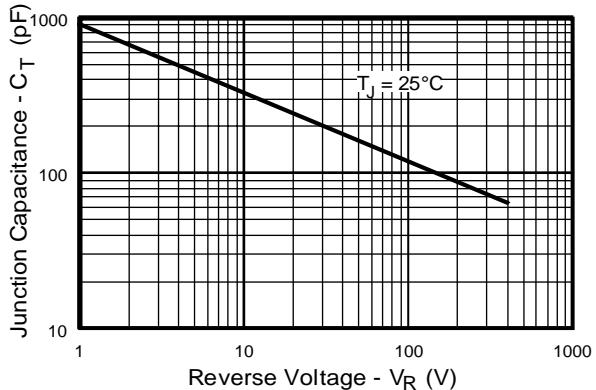




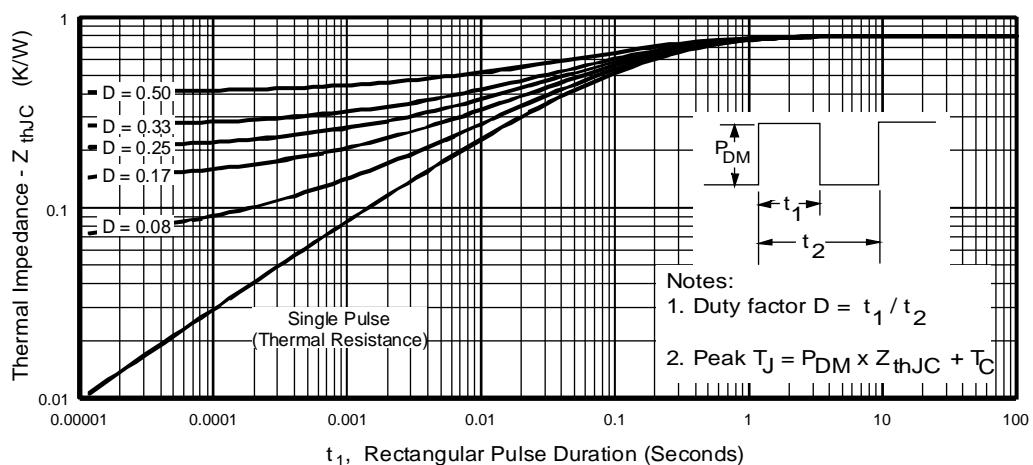
**Fig. 1** - Maximum Forward Voltage Drop vs. Instantaneous Forward Current, (per Leg)



**Fig. 2** - Typical Reverse Current vs. Reverse Voltage, (per Leg)



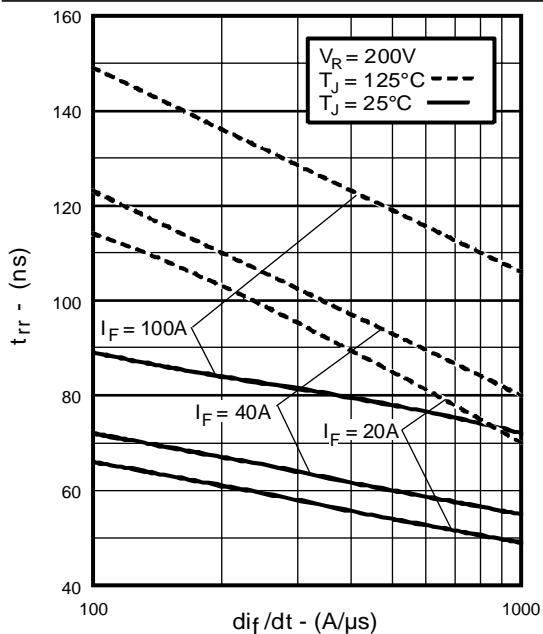
**Fig. 3** - Typical Junction Capacitance vs. Reverse Voltage, (per Leg)



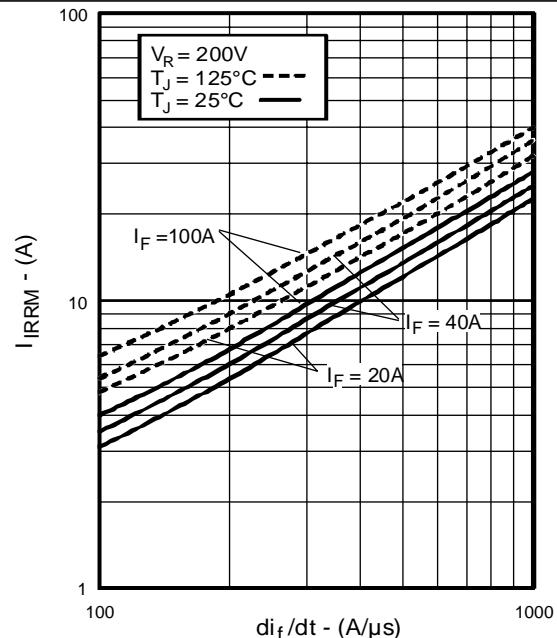
**Fig. 4** - Maximum Thermal Impedance  $Z_{thjc}$  Characteristics, (per Leg)

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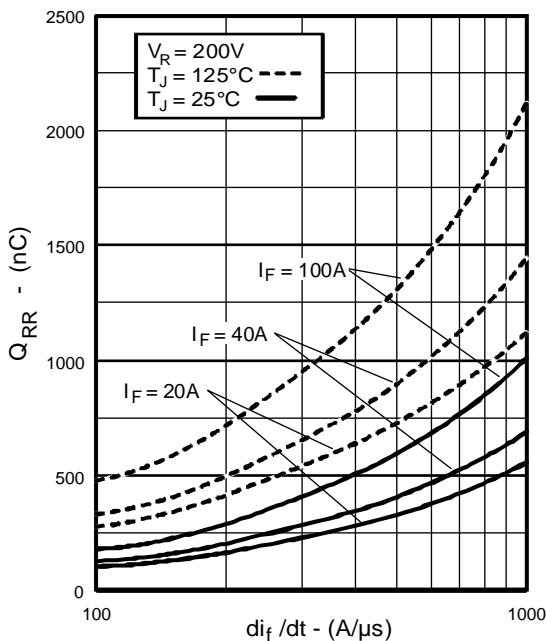
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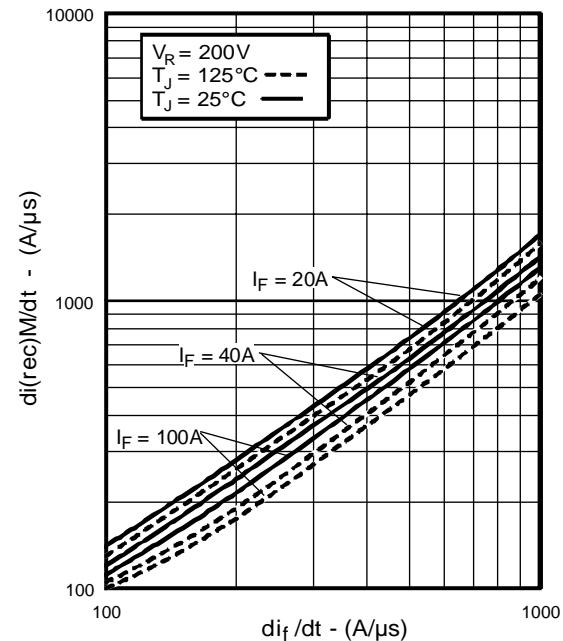
**Fig. 5 - Typical Reverse Recovery vs.  $di_f/dt$ , (per Leg)**



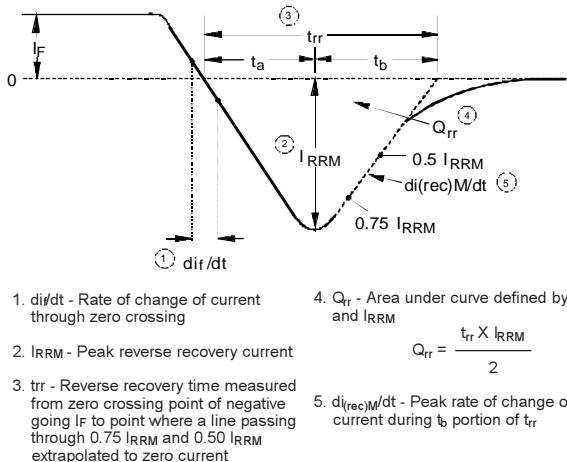
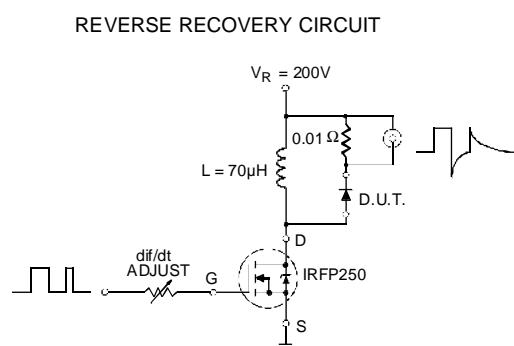
**Fig. 6 - Typical Recovery Current vs.  $di_f/dt$ , (per Leg)**



**Fig. 7 - Typical Stored Charge vs.  $di_f/dt$ , (per Leg)**

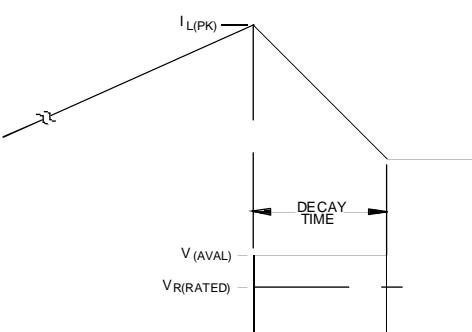
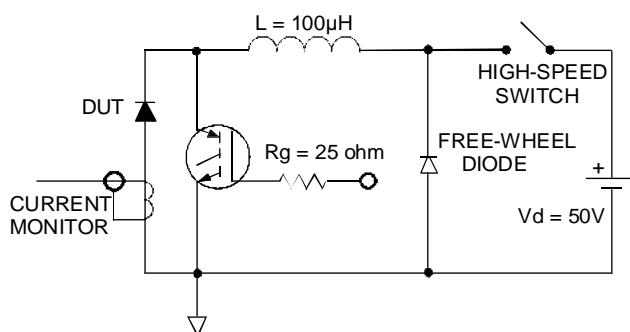


**Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $di_f/dt$ , (per Leg)**



**Fig. 9 - Reverse Recovery Parameter Test Circuit**

**Fig. 10 - Reverse Recovery Waveform and Definitions**



**Fig. 11 - Avalanche Test Circuit and Waveforms**

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<http://www.irf.com/> Data and specifications subject to change without notice. 5/97